TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCV574FT,TC74VHCV574FK

Octal Schmitt D-Type Flip Flop with 3-State Output

The TC74VHCV574 is advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high impedance state.

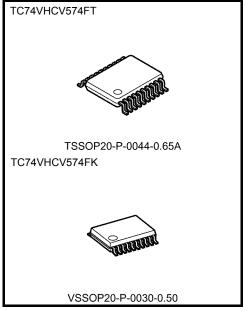
Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the TC74VHCV574 is capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output $^{\rm (Note)}$ pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, etc.

Note: Output in off-state.

Features

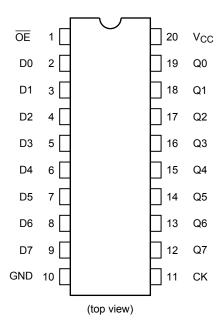
- High speed: $f_{max} = 180 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- Wide operating voltage range: $V_{CC (opr)} = 1.8 \text{ V}$ to 5.5 V
- Ouput current: $|I_{OH}|/I_{OL} = 16 \text{ mA (min) (V}_{CC} = 4.5 \text{ V})$
- Available in TSSOP and VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 574 type



Weight

TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Pin Assignment



Truth Table

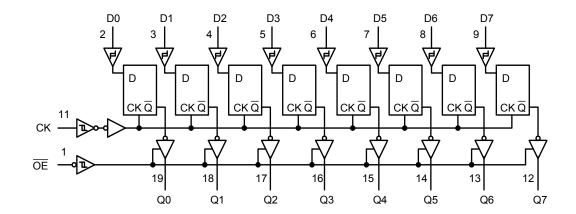
	Inputs	Output			
ŌĒ	CK	D	Output		
Н	Х	Х	Z		
L		Х	Qn		
L		L	L		
L		Н	Н		

X: Don't care

Z: High impedance

Q_n: No change

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V	-0.5 to 7.0 (Note 2)	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	
Input diode current	lıĸ	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	−65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	1.8 to 5.5	V	
Input voltage (DIR, $\overline{\text{OE}}$)	V _{IN}	0 to 5.5	V	
Output valtage	V _{OUT}	0 to 5.5 (Note 2)	V	
Output voltage		0 to V _{CC} (Note 3)		
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 20(Vcc=3.3 \pm 0.3V) 0 to 1(Vcc=5 \pm 0.5V)	ms/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 2: Output in off-state

Note 3: High or low state.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit		
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic	
				1.8	_	_	1.65	_	1.65		
				2.3	_	_	1.85	_	1.85		
Positive threshold voltage	V _P		_	3.0	_	_	2.20	_	2.20		
				4.5	_	_	3.15	_	3.15		
				5.5	_	_	3.85	_	3.85	V	
				1.8	0.15	_	_	0.15	_		
				2.3	0.45	_	_	0.45	_		
Negative threshold voltage	VN		_	3.0	0.90	_	_	0.90	_		
				4.5	1.35	_	_	1.35	_		
				5.5	1.65	_	_	1.65	_		
				1.8	0.15	_	1.05	0.15	1.05		
	Vн	_		2.3	0.20	_	1.10	0.20	1.10	٧	
Hysteresis voltage				3.0	0.30	_	1.20	0.30	1.20		
				4.5	0.40	_	1.40	0.40	1.40		
				5.5	0.50	_	1.60	0.50	1.60		
		V _{IN}		1.8	1.7	1.8	_	1.7	_		
			I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_		
High-level output voltage	V _{OH}	= V _{IH} or		4.5	4.4	4.5	_	4.4	_		
		V _{IL}	I _{OH} = −8 mA	3.0	2.58	_	_	2.48	_		
			I _{OH} = −16 mA	4.5	3.94	_	_	3.80	_	.,	
				1.8	_	0.0	0.1	_	0.1	V	
		V _{IN}	I _{OL} = 50 μA	3.0	_	0.0	0.1	_	0.1		
Low-level output voltage	V _{OL}	= V _{IH} or		4.5	_	0.0	0.1	_	0.1		
		V _{IL}	I _{OL} = 8 mA	3.0	_	_	0.36	_	0.44		
			I _{OL} = 16 mA	4.5	_	_	0.44	_	0.55		
3-state output off-state current	loz	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5V		1.8 to 5.5	_	_	±0.5	_	±5.0	μA	
Power-off leakage current	loff	$V_{IN}/V_{OUT} = 5.5 \text{ V}$		0	_	_	0.5	_	5.0	μΑ	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μA	
Quiescent supply current	Icc	V _{IN} = V _C	C or GND	5.5	_	_	2.0	_	20.0	μA	



Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t 40		2.5 ± 0.2	_	7.0	7.0	
(CK)	t _{w (H)}	_	3.3 ± 0.3	_	5.0	5.0	ns
(CK)	t _{w (L)}		5.0 ± 0.5	_	5.0	5.0	
			2.5 ± 0.2	_	5.5	5.5	
Minimum set-up time	ts	_	3.3 ± 0.3	_	3.5	3.5	ns
			5.0 ± 0.5	_	3.5	3.5	
			2.5 ± 0.2	_	2.0	2.0	
Minimum hold time	t _h	_	3.3 ± 0.3	_	1.5	1.5	ns
			5.0 ± 0.5	_	1.5	1.5	



AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Tes	est Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	- ,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			0.5 . 0.0	15	_	9.1	16.6	1.0	20.0	
			2.5 ± 0.2	50	_	11.9	19.6	1.0	23.0	
Propagation delay time	t_{pLH}		3.3 ± 0.3	15	_	6.7	13.2	1.0	15.5	ns
(CK-Q)	t_{pHL}	_	3.3 ± 0.3	50	_	8.9	16.7	1.0	19.0	115
,			5.0 ± 0.5	15	_	5.0	8.6	1.0	10.0	
			5.0 ± 0.5	50	_	6.7	10.6	1.0	12.0	
			25.02	15	_	7.6	16.1	1.0	19.0	
			2.5 ± 0.2	50	_	10.7	19.0	1.0	22.0	
3-state output enable	t_{pZL}	D = 440	22.02	15	_	5.7	12.8	1.0	15.0	
time	^t pZH	R _L = 1 kΩ	3.3 ± 0.3	50	_	8.1	16.3	1.0	18.5	ns
			5.0 ± 0.5	15	_	4.2	9.0	1.0	10.5	
				50	_	6.1	11.0	1.0	12.5	
	t _{pLZ} t _{pHZ}	R _L = 1 kΩ	2.5 ± 0.2	50	_	13.6	17.5	1.0	20.0	ns
3-state output disable time			3.3 ± 0.3	50	_	10.5	15.0	1.0	17.0	
			5.0 ± 0.5	50	_	8.2	10.1	1.0	11.5	
			2.5 ± 0.2	15	60	95	_	50	_	
				50	50	75	_	40	_	
Maximum clock	£		3.3 ± 0.3	15	80	135	_	65	_	
frequency	f _{max}	_		50	55	100	_	45	_	MHz
			E 0 + 0 E	15	130	180	_	110	_	
			5.0 ± 0.5	50	85	135	_	75	_	
			2.5 ± 0.2	50	_	_	2.0	_	2.0	
Output to output skew	t _{osLH}	(Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	ns
	t _{osHL}		5.0 ± 0.5	50	_	_	1.0	_	1.0	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Output capacitance	C _{OUT}		_		_	6	_	_	_	pF
Power dissipation capacitance	C_{PD}			(Note 2)	_	26	_	_	_	pF

Note 1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per F/F)$

And the total $C_{\mbox{\scriptsize PD}}$ when n pcs. of latch operate can be gained by the following equation:

C_{PD} (total) = 14 + 12·n



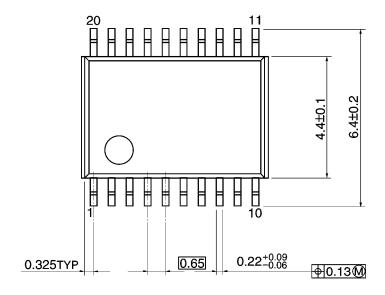
Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

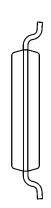
Characteristics	Symbol	Test Condition		Ta = 25°C		- Unit
Characteristics	Syllibol		V _{CC} (V)	Тур.	Max	Offic
Quiet output maximum dynamic V _{OI}	V	C ₁ = 50 pF	3.3	0.4	_	V
Quiet output maximum dynamic VOL	V_{OLP}	OL - 50 PF	5.0	0.8	_	
Quiet output minimum dunamie V	V _{OLV}	C _L = 50 pF	3.3	-0.1	_	V
Quiet output minimum dynamic V _{OL}			5.0	-0.4	_	V
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0	1	1.5	V

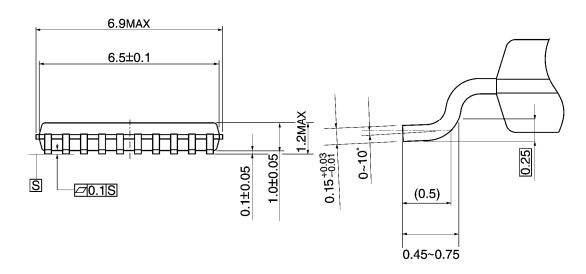
Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



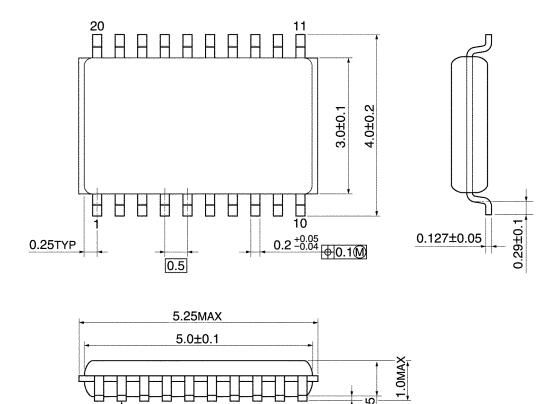




Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



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0.1±0.05

Weight: 0.03 g (typ.)

270.1

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